Docket No.: NVLUS.029CP1 (5296)

Customer No. 20,995

INFORMATION DISCLOSURE STATEMENT

Applicant : Basol et al.

App. No : 10/822,424

Filed : April 12, 2004

For : SYSTEM FOR ELECTROPOLISHING AND ELECTROCHEMICAL

MECHANICAL POLISHING

Examiner : Zulmariam Mendez

Art Unit : 1709

Conf. No. : 4984

CERTIFICATE OF EFS WEB TRANSMISSION

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August 14, 2007

(Date)

Adam Gilbert, Reg. No. 59,967

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

Enclosed for filing in the above-identified application is a PTO/SB/08 Equivalent listing 25 references to be considered by the Examiner. References numbered 16-23 are of record in U.S. patent application No. 09/283,024, filed March 30, 1999, which is relied upon for an earlier filing date under 35 U.S.C. § 120. Accordingly, copies of references numbered 16-23 are not submitted pursuant to 37 C.F.R. § 1.98(d).

This Information Disclosure Statement is being filed before the mailing date of a final action and before the mailing of a Notice of Allowance. This Statement is accompanied by the fees set forth in 37 C.F.R. § 1.17(p). The Commissioner is hereby authorized to charge any additional fees which may be required or to credit any overpayment to Account No. 11-1410.

Respectfully submitted,

KNOBBE, MARTENS, OLSON & BEAR, LLP

Dated: 4/14/67

By: Oda At

Adam Gilbert Registration No. 59,967 Attorney of Record

Customer No. 20,995 (949) 760-0404

4126063; 081007

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Multiple sheets used when necessary)
SHEET 1 OF 2

U.S. PATENT DOCUMENTS					
Examiner Initials	Cite No.	Document Number Number - Kind Code (if known) Example: 1,234,567 B1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear
	1	5,553,527	09-10-1996	Harrison	
	2	5,660,708	08-26-1997	Tezuka et al.	
-	3	6,582,281	06-24-2003	Doan et al.	

FOREIGN PATENT DOCUMENTS						
Examiner Initials	Cite No.	Foreign Patent Document Country Code-Number-Kind Code Example: JP 1234567 A1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear	T ¹
	4	DE 2008664	09-09-1971	Jostan		
	5	DE 4324330	03-02-1994	Schneider		
	6	FR 2763343	05-13-1998	Reidsema et al.		
	7	GB 1350070	04-18-1974	Luttmer et al.		
	8	JP 6-108285	04-22-1994	Ezawa et al.		
	9	JP 11-054479	02-26-1999	Nakajima		
	10	WO 97/01657	01-16-1997	Billman		
	11	WO 98/27585	06-25-1998	Andricacos et al.		
	12	WO 99/64647	12-16-1999	Adams et al.		
	13	WO 00/03426	01-20-2000	Wang et al.		
	14	WO 00/26443	05-11-2000	Talieh		
	15	WO 02/064314	08-22-2002	Emesh et al.		

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ¹
	16	Contolini et al., "Electrochemical Planarization for Multilevel Metallization," J. Electrochem. Soc., 1994, Vol. 141, pp. 2503-2510.	
	17	Kelly et al, "Leveling and Microstructural Effects of Additives for Copper Electrodeposition," J. Electrochem. Soc., 1999, Vol. 146, No. 7, pp. 2540-2545.	
	18	Madore et al., "Blocking inhibitors in Catholic Leveling," <u>I Theoretical Analysis</u> , December 1997, pp. 3927-3942.	
	19	Mikkola et al., "Investigation of the Roles of the Additive Components for Second Generation Copper Electroplating Chemistries Used for Advanced Interconnect Metallization," 2000 IEEE, June 2000, pp. 117-119, IEEE Electron Devices Society.	

Examiner	Signature
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Date Considered

*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

T1 - Place a check mark in this area when an English language Translation is attached.

		P TO/OB/00 Equivalent
	Application No.	10/822,424
INFORMATION DISCLOSURE	Filing Date	April 12, 2004
STATEMENT BY APPLICANT	First Named Inventor	Bulent M. Basol
STATEMENT BY AFFEIGANT	Art Unit	1742
(Multiple sheets used when necessary)	Examiner	Zulmariam Mendez
SHEET 2 OF 2	Attorney Docket No.	NVLUS.029CP1(5296)

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	Т1
	20	Rubinstein, "Tampongalvanisieren in der Praxis, Teil 1," Galvanotechnik, 1988, Vol. 79, No. 10, pp. 3263-3270.	
	21	Joseph M. Steigerwald et al., "Chemical Mechanical Planarization of Microelectronic Materials," A Wiley-Interscience Publication, 1997 by John Wiley & Sons, Inc. pp 212-222.	
	22	Steigerwald et al., "Pattern Geometry Effects in the Chemical-Mechanical Polishing of Inlaid Copper Structures," J. Electrochem. Soc., 1994, Vol. 141, pp. 2842-2848.	
	23	West et al., "Pulse Reverse Copper Electrodeposition in High Aspect Ratio Trenches and Vias," J. Electrochem. Soc., 1998, Vol. 145, pp. 3070-3073.	
	24	Office Action for U.S. Patent Application No. 10/391,924, dated April 30, 2007	
	25	Response to Office Action for U.S. Patent Application No. 10/391,924, dated April 30, 2007	

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Examiner Signature Date Considered		Pato Galloradioa